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FOREWORD

This issue of Journal of Integrated Circuits and Systems (JICS) includes papers on process, materials, devices, and modeling. These papers have been selected from the presentations given at SBMicro2009 (24th Symposium on Microelectronics Technology and Devices), which has been held in Natal, Brazil in 2009. Among the contributions presented at SBMicro2009 conference, only a few best rated by the reviewers were selected by the JICS Editorial Board and have been invited to submit an extended version. These papers have been submitted to usual reviewing process with the help of external experts. In this issue also spontaneous submissions have been considered.

We would like to thank the authors for their effort in preparing these high quality papers, as well as the reviewers for their help on paper selection, which guarantees the scientific level of this issue. We sincerely hope that JICS readers will enjoy these contributions.

João Antonio Martino

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